## NSN 5961-00-006-5540

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-006-5540 **Inclosure Material:** Glass and metal **Overall Length:** 0.260 inches **Terminal Length:** 0.150 inches **Overall Height:** 0.080 inches **Overall Width:** 0.150 inches **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage, dc all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector absolute all transistor **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** 

No **Fiig:** 

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**Demilitarization:**